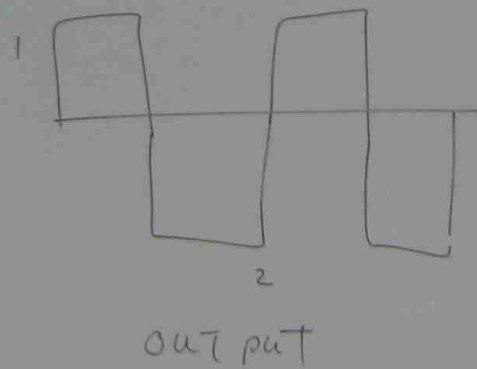
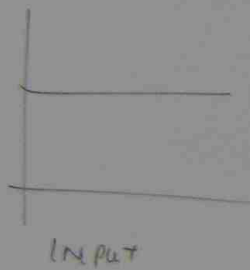
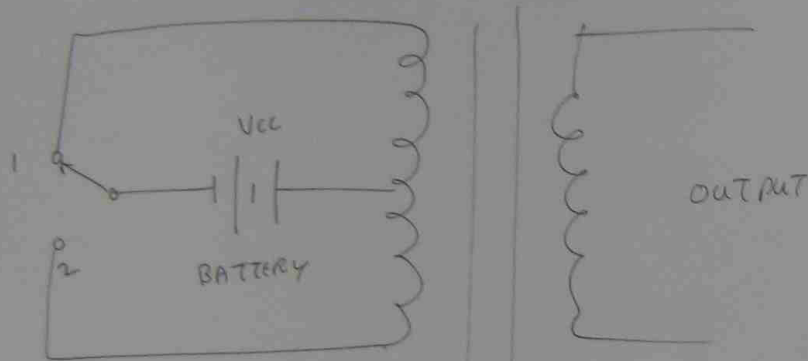
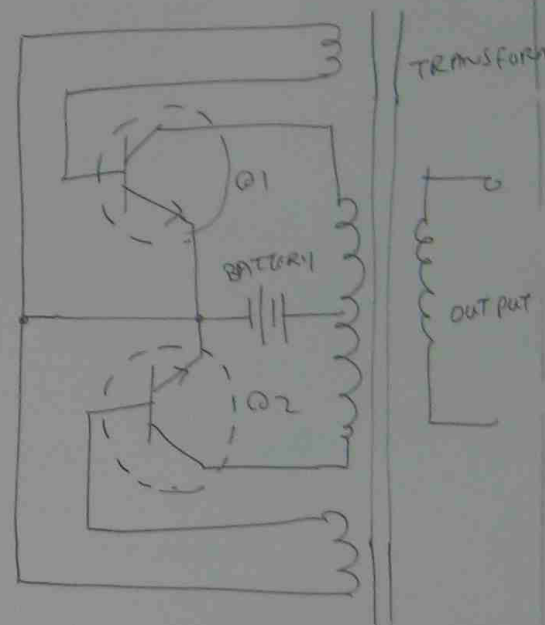


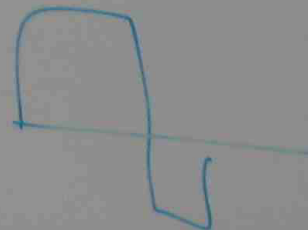
BASIC INVERTER PRINCIPLE CIRCUIT

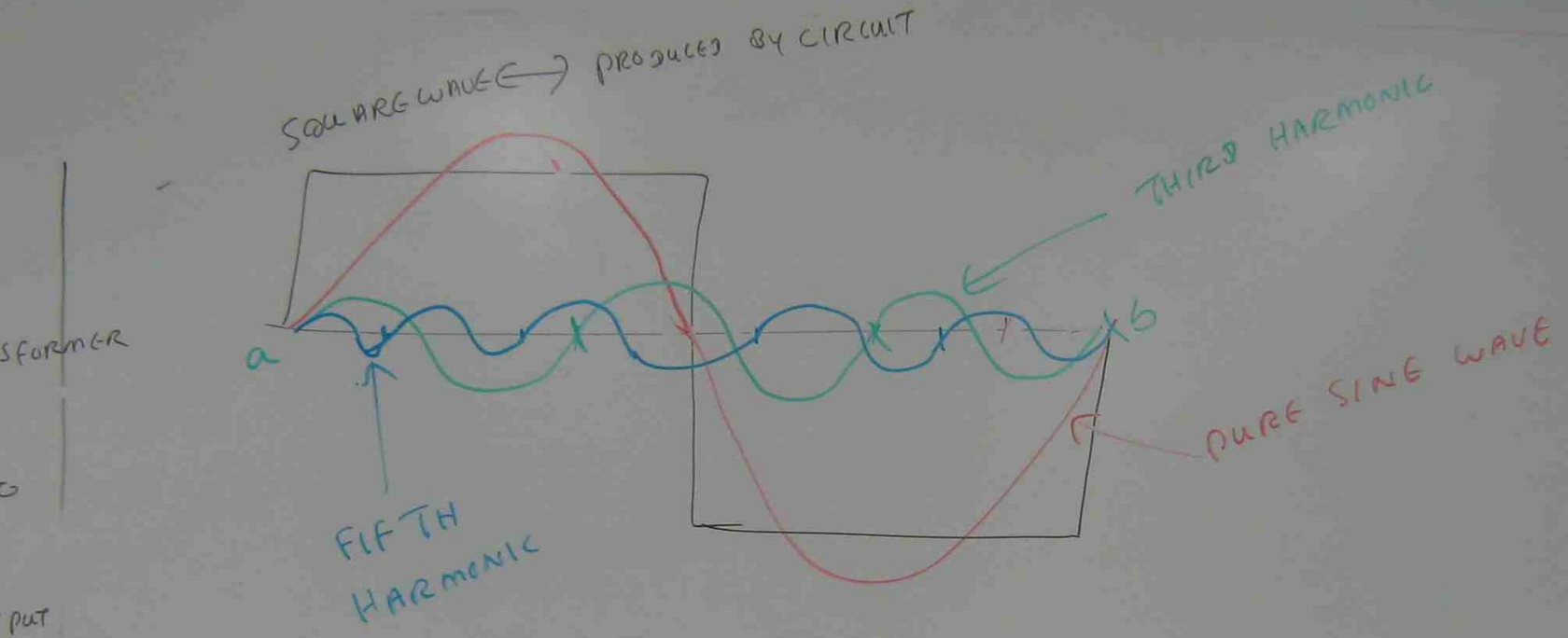


TRANSISTOR SWITCHING CIRCUIT FOR INVERTER



$Q_1, Q_2 = \text{TRANSISTOR}$

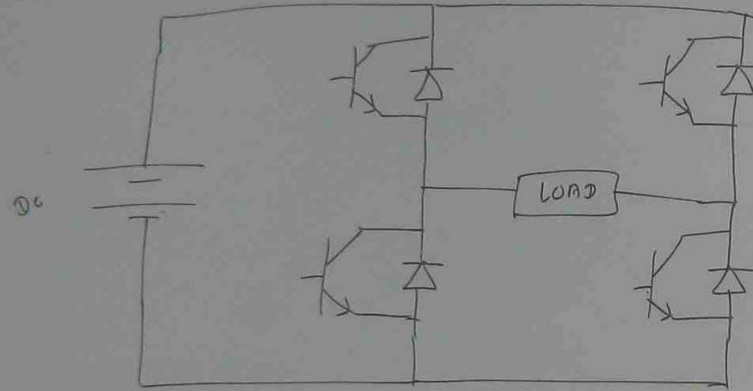




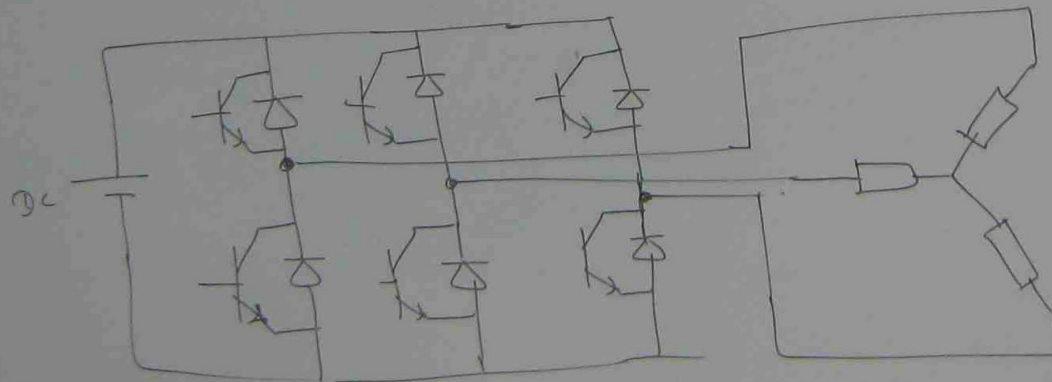
FUNDAMENTAL SINE WAVE + THIRD HARMONIC + FIFTH HARMONIC \approx SQUARE WAVE

By FILTERING OUT THE 3rd HARMONIC AND 5th HARMONIC,
APPROXIMATE SINE WAVE CAN BE LEFT.

H BRIDGE INVERTER



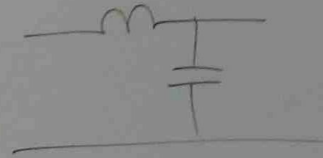
THREE PHASE INVERTER



CAPACITORS AND INDUCTORS CAN BE USED TO FILTER THE WAVE FORM.

IF THE DESIGN INCLUDE A TRANSFORMER, FILTERING CAN BE APPLIED TO THE PRIMARY (OR) TO BOTH SIDES.

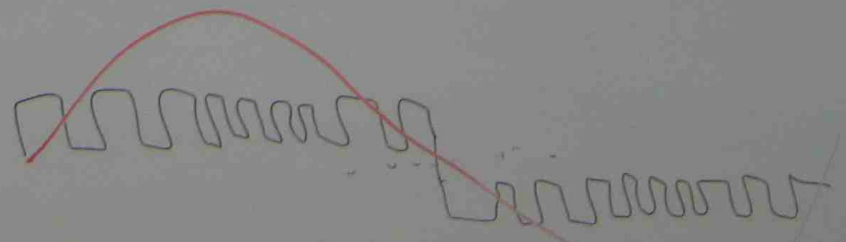
LOW PASS FILTERS ARE APPLIED TO ALLOW THE FUNDAMENTAL COMPONENT OF THE WAVE FORM TO PASS TO THE OUT PUT WHILE LIMITING THE PASSAGE OF THE HARMONIC COMPONENTS.

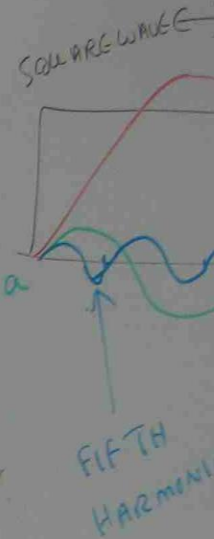
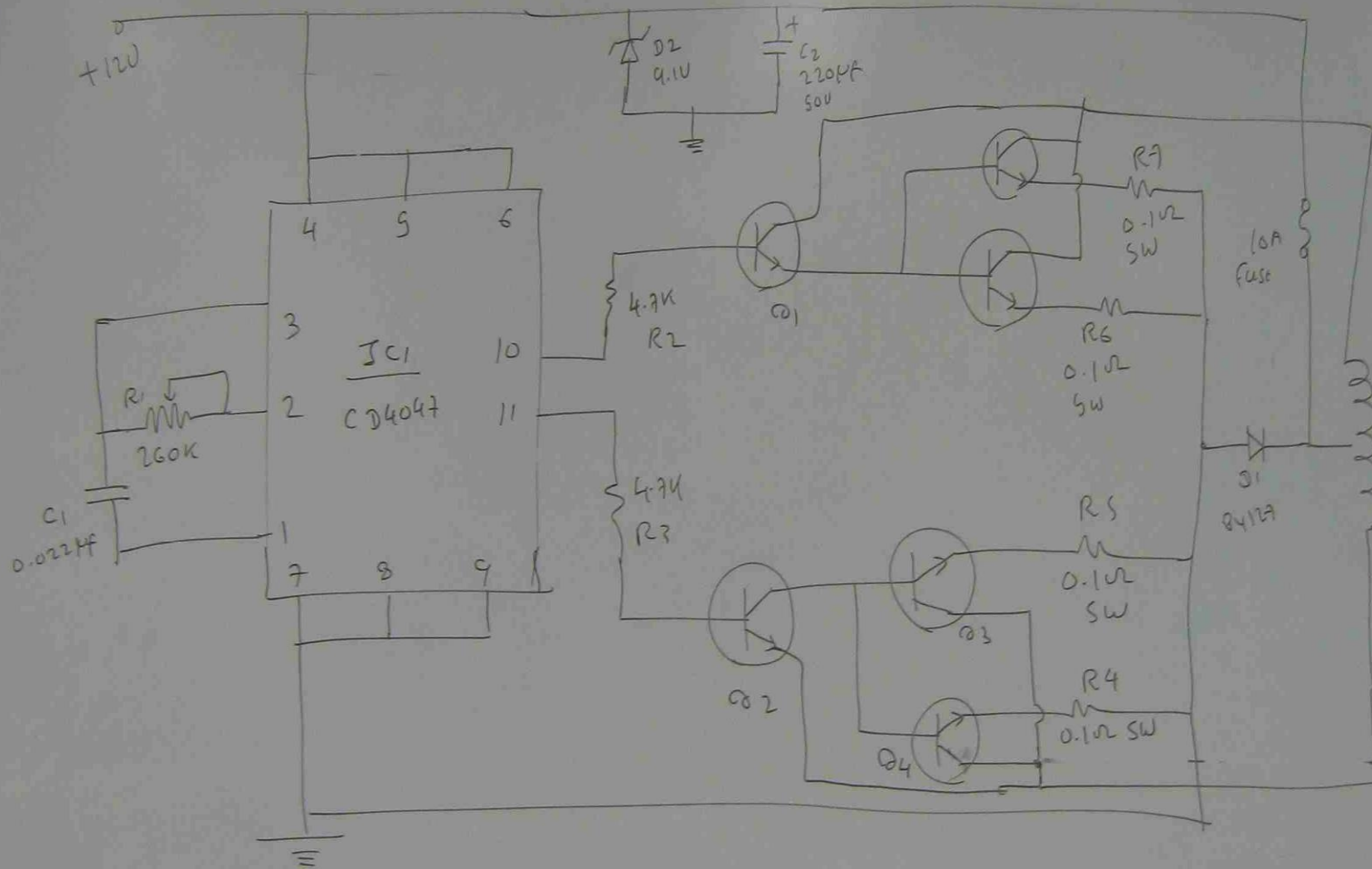


P.W.M TECHNOLOGY (PULSE WIDTH MODULATION TECHNOLOGY)

MODULATING (OR) REGULATING THE WIDTH OF A SQUARE WAVE PULSE IS OFTEN USED AS A METHOD OF REGULATING (OR) ADJUSTING AN INVERTER'S OUTPUT VOLTAGE.

WHEN VOLTAGE CONTROL IS NOT REQUIRED, A FIXED PULSE WIDTH CAN BE SELECTED TO REDUCE (OR) ELIMINATE HARMONICS.





FUNDAMENTAL SIN

By FILTERING

APPROXIMATE

100W

INVERTER

$Q_1, Q_2 = \text{TIP 122}$

$Q_3 \text{ TO } Q_4 = 2N3055$

MODIFIED SINE WAVE

- THE MODIFIED SINE WAVE IS THE CHEAP AND EASY SOLUTION FOR POWERING AC DEVICES BUT NOT ALL EQUIPMENTS ESPECIALLY COMPUTER AND MEDICAL WILL NOT PROPERLY WORK WITH IT. FILTER IS REQUIRED TO PROVIDE PURE SINE WAVE.

VOLTAGE

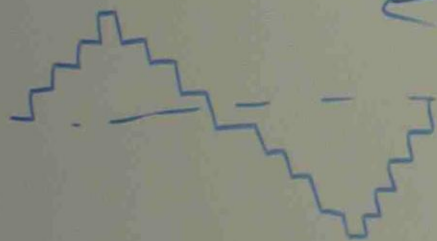
ITS

IT'S LEVEL

TAGE DISTANCE TRANSMISSION



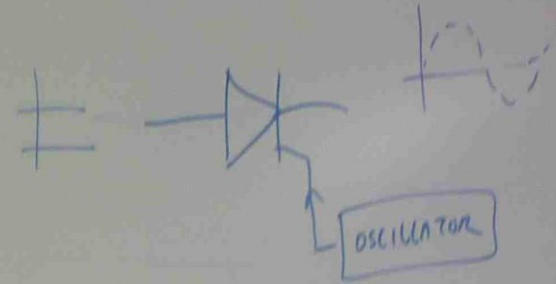
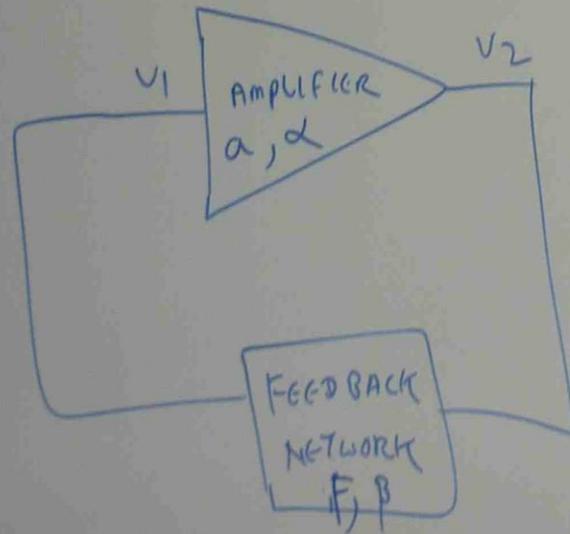
ED SINE WAVE



← INVERTER

OSCILLATOR FOR INVERTER CIRCUIT

RESISTORS, INDUCTORS, CAPACITORS AND AN AMPLIFIER WITH HIGH GAIN ARE BASIC COMPONENTS OF AN OSCILLATOR. IN DESIGNING OSCILLATORS, INSTEAD OF USING DISCRETE PASSIVE COMPONENTS (RESISTORS, INDUCTORS AND CAPACITORS), CRYSTAL OSCILLATORS ARE A BETTER CHOICE BECAUSE OF THEIR EXCELLENT FREQUENCY STABILITY AND WIDE FREQUENCY RANGE.



$$a = \text{GAIN} = \frac{V_2}{V_1}$$

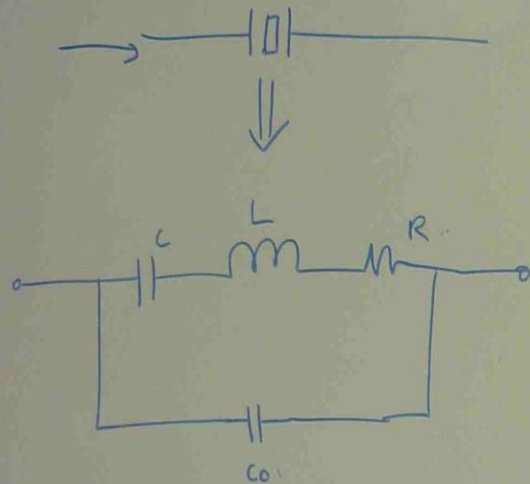
$$\alpha = \text{PHASE SHIFT}$$

$$F = \text{TRANSFER FUNCTION}$$

$$\beta = \text{PHASE SHIFT OF FEED BACK SIGNAL}$$

$$|F| \times |a| \geq 1 \rightarrow \text{OSCILLATION}$$

CHARACTERISTICS OF CRYSTAL OSCILLATOR



$Z \rightarrow 0 \rightarrow$ CRYSTAL OSCILLATOR = SERIES RESONANCE FREQUENCY

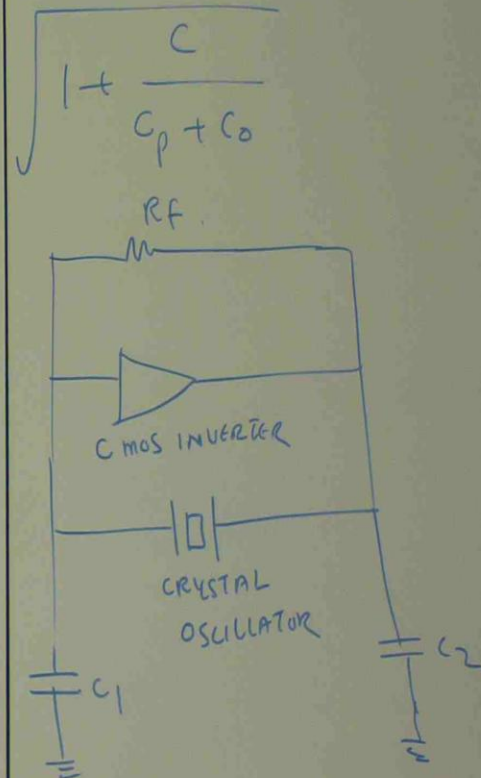
$$f_{ser} = \frac{1}{2\pi\sqrt{LC}}$$

$Z \rightarrow \infty$ CRYSTAL OSCILLATOR = PARALLEL RESONANCE FREQUENCY

$$f_{par} = f_{ser} \sqrt{1 + \frac{C}{C_0}}$$

$$f_{par} = \frac{1}{2\pi\sqrt{LC}} \times$$

$$C_p = \frac{C_1 C_2}{C_1 + C_2}$$



TO IMPROVE THE FREQUENCY RESPONSE OF CRYSTAL OSCILLATOR, C_1 AND C_2 ARE TO BE CONNECTED.

BASED ON C_1 , C_2 VALUES, IT DETERMINES THE OSCILLATOR FREQUENCY

$$f = \frac{C_1}{C_2}$$

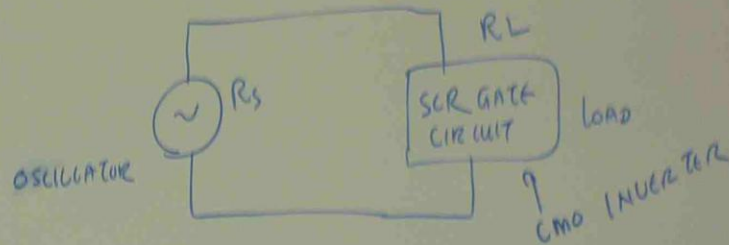
IN AN OSCILLATOR CIRCUIT, THE CMOS INVERTER OPERATES IN THE LINEAR MODE AND WORKS AS AN AMPLIFIER.

THE PHASE SHIFT PROVIDED BY THE INVERTER IS 180 DEGREES.

FOR $C_1 = C_2$, PHASE SHIFT IS 180

INPUT IMPEDANCE OF OSCILLATOR $Z_i = \frac{R_f}{a}$

MAXIMUM POWER TRANSFER



R_s = SOURCE IMPEDANCE

R_L = LOAD IMPEDANCE

IF $R_s = R_L \rightarrow$ MAXIMUM POWER TRANSFER

OSCILLATOR IS RUNNING AT PARALLEL RESONANCE CONDITION.

OSCILLATOR PARALLEL RESONANCE = SOURCE IMPEDANCE
RESISTANCE R_p

$$R_p = \frac{1}{R \omega^2 (C_0 + C_p)^2}$$

$$\omega = 2\pi f$$

↑ FREQUENCY AT WHICH THE
OSCILLATOR IS OPERATING

R_p SHOULD MATCH THE INPUT IMPEDANCE
OF THE CMOS INVERTER TO ALLOW
MAXIMUM POWER TRANSFER AS WELL AS
TO EFFECTIVELY DRIVE THE SCR GATE
CIRCUIT OF INVERTER.

Ex

A CRYSTAL OSCILLATOR HAS THE FOLLOWING PARAMETERS.

$$C_p = 30 \text{ pF}$$

$$C_0 = 7 \text{ pF}$$

$$R = 20 \Omega \text{ AT } 5 \text{ MHz}$$

FOR A CMOS INVERTER WITH AN OPEN LOOP GAIN

$a = 100$, CALCULATE THE VALUE OF FEED BACK

RESISTOR.

USE THE FOLLOWING CONCEPT

THE VALUE OF FEEDBACK = Z_i (OR) $R_p \times \text{GAIN}$
RESISTOR

$$R_f = R_p \times a$$

$$R_p = \frac{1}{R \omega^2 (C_o + C_p)^2}$$

$$\omega = 2\pi f$$

$$= 2\pi \times 5 \times 10^6$$

$$C_o = 7 \times 10^{-12} \text{ F}$$

$$C_p = 30 \times 10^{-12} \text{ F}$$

$$R_p = \frac{1}{80 \times (2\pi \times 5 \times 10^6)^2 (7 \times 10^{-12} + 30 \times 10^{-12})^2}$$

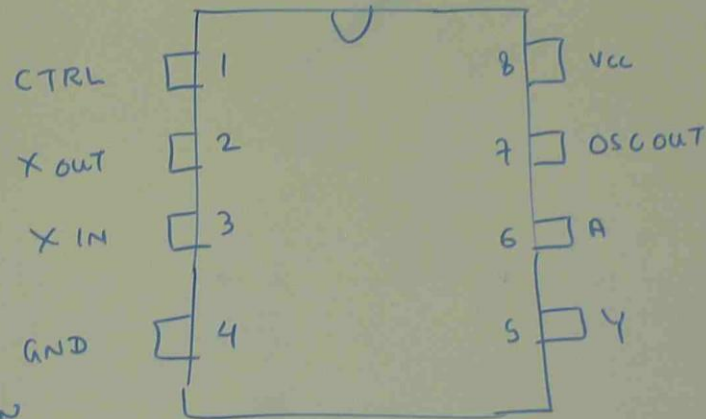
$$= 10,000 \Omega \approx 10 \text{ k}\Omega$$

$$R_F = R_p \times a = 10,000 \times 100 = 10,000,000$$

$$= 1 \text{ M}\Omega$$

TI LUC 1404 (TEXAS INSTRUMENT)

THE TI LUC 1404 IC IS A DUAL INVERTER GATE THAT IS VERY SUITABLE FOR OSCILLATOR APPLICATIONS.



PIN OUT DIAGRAM
FOR TI (LUC 1404)

CONNECTION

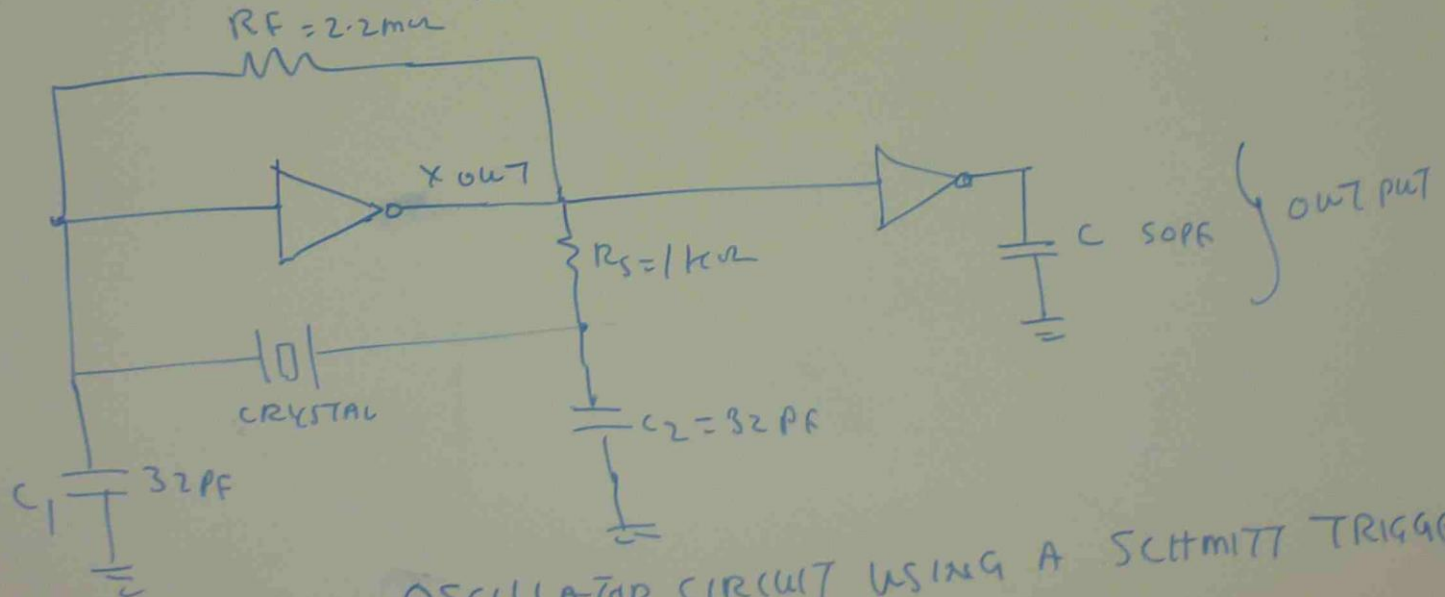
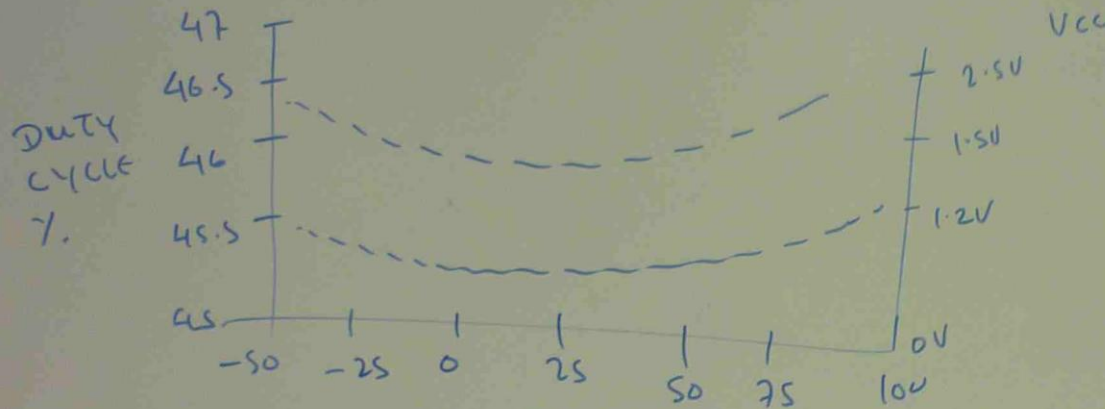
X_{IN} - CONNECTED TO UNBUFFERED INVERTER

X_{OUT} - OUT PUT OF THIS INVERTER

IT IS CONNECTED TO THE INPUT OF ANOTHER INVERTER TO GET A CLEAN SIGNAL

THE CRYSTAL IS CONNECTED BETWEEN X_{IN} & X_{OUT}

V_{CC} 1.2 \rightarrow 2.5V up To 5V



OSCILLATOR CIRCUIT USING A SCHMITT TRIGGER
INVERTER

OPERATIONAL REQUIREMENTS

- GOOD POWER SUPPLY DECOUPLING IS NECESSARY TO SUPPRESS NOISE ON THE SUPPLY LINE
- LOW RESONANCE CERAMIC CAPACITORS SHOULD BE USED AS CLOSE TO THE CIRCUIT AS POSSIBLE. THE REFERENCE VALUE IS 100 nF
- CONNECTIONS IN THE LAYOUT SHOULD BE AS SHORT AS POSSIBLE TO KEEP THE RESISTANCE AND INDUCTANCE LOW.
- TO REDUCE CROSSTALK, STANDARD PCB DESIGN TECHNIQUES SHOULD BE USED.
- WITHOUT CRYSTAL, THE OSCILLATOR SHOULD NOT OSCILLATE. TO CHECK THIS, THE CRYSTAL IN A CMOS OSCILLATOR CAN BE REPLACED BY ITS EQUIVALENT PARALLEL RESONANT RESISTANCE.

SINE WAVE INVERTER DESIGN

DC CURRENT - STEADY AND CONSTANT VOLTAGE

USED FOR DIGITAL CIRCUITS

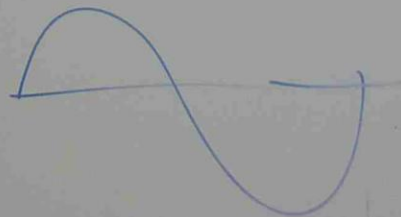
AC CURRENT - CAN EASILY BE CHANGED IT'S LEVEL

REDUCE POWER LOSS

SUITABLE FOR HIGH VOLTAGE DISTANCE TRANSMISSION

AC WAVE -

- SQUARE WAVE
- MODIFIED SINE WAVE | STEP SINE WAVE
- PURE SINE WAVE



MODIFIED

THE

SOLUTION

ESPEC

WORK

PURE

TO COMBAT THE SURGE PROBLEM, SNUBBER CIRCUIT
CAN REDUCE OR ELIMINATE ANY SEVERE VOLTAGE
AND CURRENTS.

COMPOSED OF SIMPLY RESISTOR AND CAPACITOR
PLACED ACROSS EACH SWITCH ALLOWS ANY CURRENT
OR VOLTAGE SPIKES TO BE SUPPRESSED BY
CRITICALLY DAMPING THE SURGE AND PROTECTING
THE SWITCH FROM DAMAGE.

